IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Arup Bhattacharyya

Examiner: Trong Phan

Serial No.:

10/075484

Group Art Unit: 2818

Filed:

February 12, 2002

Docket: 1303.043US1

Title:

ASYMMETRIC BAND-GAP ENGINEERED NONVOLATILE MEMORY

DEVICE

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Applicant would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

Serial/Patent No. 09/945507	Filing Date August 30, 2001	Attorney Docket 1303.014US1	Title FLASH MEMORY WITH LOW TUNNEL BARRIER INTERPOLY INSULATORS
09/944985	August 30, 2001	1303.023US1	SCALABLE FLASH/NV STRUCTURES & DEVICES WITH ENHANCED ENDURANCE
10/232848	August 30, 2002	1303.073US1	ONE-DEVICE NON-VOLATILE RANDOM ACCESS MEMORY CELL

Respectfully submitted,

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